74ABT827

10-bit buffer/line driver; non-inverting; 3-state Rev. 5 — 7 November 2011

Product data sheet

General description 1.

The 74ABT827 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT827 10-bit buffers provide high performance bus interface buffering for wide data/address paths or buses carrying parity. They have NOR Output Enables (OE0, OE1) for maximum control flexibility.

Features and benefits 2.

- Ideal where high speed, light loading, or increased fan-in are required
- Flow-through pinout architecture for microprocessor oriented applications
- Output capability: +64 mA and –32 mA
- Power-up 3-state
- Inputs are disabled during 3-state mode
- Latch-up protection exceeds 500 mA per JESD78B class II level A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V

Ordering information 3.

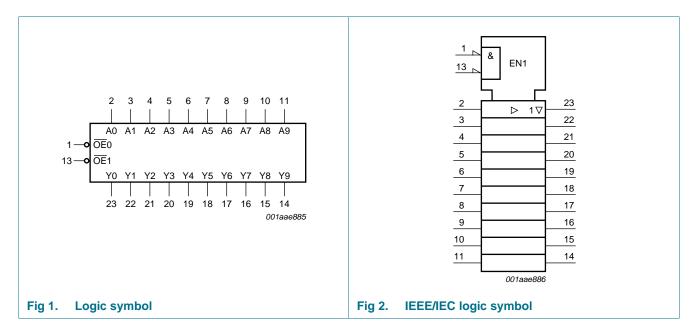
Table 1. **Ordering information**

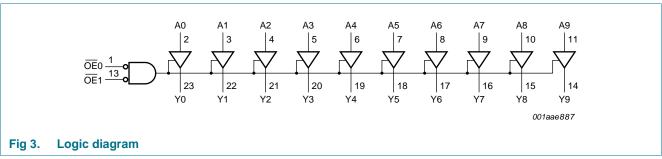
Type number	Package										
	Temperature range	Name	Description	Version							
74ABT827D	–40 °C to +85 °C	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1							
74ABT827DB	–40 °C to +85 °C	SSOP24	plastic shrink small outline package; 24 leads; body width 5.3 mm	SOT340-1							
74ABT827PW	–40 °C to +85 °C	TSSOP24	plastic thin shrink small outline package; 24 leads; body width 4.4 mm	SOT355-1							



10-bit buffer/line driver; non-inverting; 3-state

4. Functional diagram

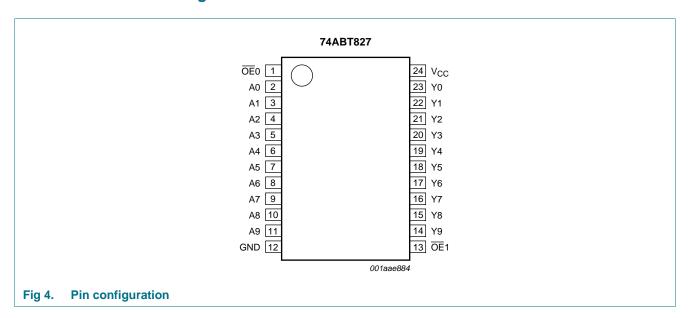




10-bit buffer/line driver; non-inverting; 3-state

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
OE0	1	output enable input (active LOW)
A0 to A9	2, 3, 4, 5, 6, 7, 8, 9, 10, 11	data input
GND	12	ground (0 V)
OE1	13	output enable input (active LOW)
Y0 to Y9	23, 22, 21, 20, 19, 18, 17, 16, 15, 14	data output
V_{CC}	24	supply voltage

6. Functional description

6.1 Function table

Table 3. Function table[1]

Inputs		Output	Operating mode
OE n	An	Yn	
L	L	L	transparent
L	Н	Н	transparent
Н	X	Z	high-impedance

^[1] H = HIGH voltage level;

L = LOW voltage level;

X = don t care;

Z = high-impedance OFF-state.

74ABT827

All information provided in this document is subject to legal disclaimers.

10-bit buffer/line driver; non-inverting; 3-state

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		<u>[1]</u> –1.2	+7.0	V
Vo	output voltage	output in OFF-state or HIGH-state	[<u>1</u>] -0.5	+5.5	V
I _{IK}	input clamping current	V _I < 0 V	-18	-	mA
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Io	output current	output in LOW-state	-	128	mA
Tj	junction temperature		[2] _	150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		4.5	-	5.5	V
VI	input voltage		0	-	V_{CC}	V
V_{IH}	HIGH-level input voltage		2.0	-	-	V
V_{IL}	LOW-level input voltage		-	-	0.8	V
I _{OH}	HIGH-level output current		-32	-	-	mA
I _{OL}	LOW-level output current		-	-	64	mA
$\Delta t/\Delta V$	input transition rise and fall rate		0	-	5	ns/V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C

^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.

10-bit buffer/line driver; non-inverting; 3-state

9. Static characteristics

Table 6. Static characteristics

mbol Parameter Conditions	Conditions			25 ℃		_40 °C +	40 °C to +85 °C		
raiailletei	Conditions		Min		May			Unit	
input elemning veltage	V - 4.5.V: 1 - 19.mA						IVIAA	V	
	**		-1.2	-0.9		-1.2	-	V	
•	=		0.5	0.0		0.5		\ /	
· onago								V	
							-	V	
							-	V	
LOW-level output voltage	$V_{CC} = 4.5 \text{ V}; I_{OL} = 64 \text{ mA};$ $V_{I} = V_{IL} \text{ or } V_{IH}$		-	0.42	0.55	-	0.55	V	
input leakage current	V_{CC} = 5.5 V; V_I = GND or 5.5 V		-	±0.01	±1.0	-	±1.0	μΑ	
power-off leakage current	V_{CC} = 0 V; V_{I} or $V_{O} \le 4.5$ V		-	±5.0	±100	-	±100	μΑ	
power-up/power-down output current	$V_{CC} = 2.0 \text{ V}; V_O = \underline{0.5} \text{ V};$ $V_I = \text{GND or } V_{CC}; \overline{\text{OE}} \text{n HIGH}$	[1]	-	±5.0	±50	-	±50	μΑ	
OFF-state output current	$V_{CC} = 5.5 \text{ V}; V_I = V_{IL} \text{ or } V_{IH}$								
	V _O = 2.7 V		-	5.0	50	-	50	μΑ	
	V _O = 0.5 V		-	-5.0	-50	-	-50	μΑ	
output leakage current	HIGH-state; $V_O = 5.5 \text{ V}$; $V_{CC} = 5.5 \text{ V}$; $V_I = \text{GND or } V_{CC}$		-	5.0	50	-	50	μΑ	
output current	$V_{CC} = 5.5 \text{ V}; V_{O} = 2.5 \text{ V}$	[2]	-180	-80	-50	-180	-50	mΑ	
supply current	V_{CC} = 5.5 V; V_I = GND or V_{CC}								
	outputs HIGH-state		-	0.5	250	-	250	μΑ	
	outputs LOW-state		-	25	38	-	38	mΑ	
	outputs disabled		-	0.5	250	-	250	μΑ	
additional supply current	per input pin; V_{CC} = 5.5 V; one input at 3.4 V; other inputs at V_{CC} or GND	[3]							
	outputs enabled		-	0.5	1.5	-	1.5	mΑ	
	outputs 3-state, one data input		-	0.01	50	-	50	mA	
	outputs 3-state; one enable input		-	0.5	1.5	-	1.5	mΑ	
input capacitance	$V_I = 0 \text{ V or } V_{CC}$		-	4	-	-	-	pF	
output capacitance	outputs disabled; $V_O = 0 \text{ V}$ or V_{CC}		-	7	-	-	-	pF	
	input clamping voltage HIGH-level output voltage LOW-level output voltage input leakage current power-off leakage current power-up/power-down output current OFF-state output current output leakage current aupply current additional supply current	$ Input clamping voltage V_{CC} = 4.5 \text{ V; } I_{IK} = -18 \text{ mA} V_{II} = V_{IL} \text{ or } V_{IH} V_{CC} = 4.5 \text{ V; } I_{OH} = -3 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -3 \text{ mA} V_{CC} = 5.0 \text{ V; } I_{OH} = -3 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -3 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{CC} = 5.5 \text{ V; } V_{I} = \text{ GND or } 5.5 \text{ V} V_{I} = \text{ GND or } 5.5 \text{ V} V_{I} = \text{ GND or } 5.5 \text{ V} V_{I} = \text{ GND or } 5.5 \text{ V} V_{I} = \text{ GND or } 5.5 \text{ V} V_{I} = \text{ GND or } V_{CC} V_{CC} V_{CC} = 5.5 \text{ V; } V_{I} = \text{ GND or } V_{CC} V_{CC} = 5.5 \text{ V; } V_{I} = \text{ GND or } V_{CC} V_{CC} $	$ Input clamping voltage V_{CC} = 4.5 \text{ V; } I_{IK} = -18 \text{ mA} V_{IC} = 4.5 \text{ V; } I_{IK} = -18 \text{ mA} V_{IC} = 4.5 \text{ V; } I_{IK} = -18 \text{ mA} V_{IC} = 4.5 \text{ V; } I_{OH} = -3 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -3 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -3 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{CC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{IC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{IC} = 4.5 \text{ V; } I_{OH} = -32 \text{ mA} V_{IC} = -32 \text{ mA} V_{IC$	$ Input clamping voltage V_{CC} = 4.5 \ V; \ I_{IK} = -18 \ mA $		N N N N N N N N N	Normal Normal	Note Note	

^[1] This parameter is valid for any V_{CC} between 0 V and 2.1 V with a transition time of up to 10 ms. For V_{CC} = 2.1 V to V_{CC} = 5 V \pm 10 %, a transition time of up to 100 μ s is permitted.

^[2] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

^[3] This is the increase in supply current for each input at 3.4 V.

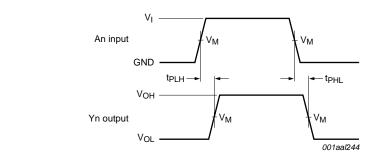
10-bit buffer/line driver; non-inverting; 3-state

10. Dynamic characteristics

Table 7. Dynamic characteristics GND = 0 *V; for test circuit, see <u>Figure 7.</u>*

Symbol	Parameter	Conditions		25 °C; _C = 5.0		-40 °C to V _{CC} = 5.0	Unit	
			Min	Тур	Max	Min	Max	
t_{PLH}	LOW to HIGH propagation delay	An to Yn; see Figure 5	1.1	3.0	4.4	1.1	4.8	ns
t _{PHL}	HIGH to LOW propagation delay	An to Yn; see Figure 5	1.1	2.9	4.1	1.1	4.7	ns
t _{PZH}	OFF-state to HIGH propagation delay	OEn to Yn; see Figure 6	1.6	3.7	5.1	1.6	5.9	ns
t _{PZL}	OFF-state to LOW propagation delay	OEn to Yn; see Figure 6	2.6	4.6	5.9	2.6	6.9	ns
t _{PHZ}	HIGH to OFF-state propagation delay	OEn to Yn; see Figure 6	2.0	4.8	6.3	2.0	6.8	ns
t _{PLZ}	LOW to OFF-state propagation delay	OEn to Yn; see Figure 6	2.5	5.1	6.6	2.5	6.9	ns

11. Waveforms

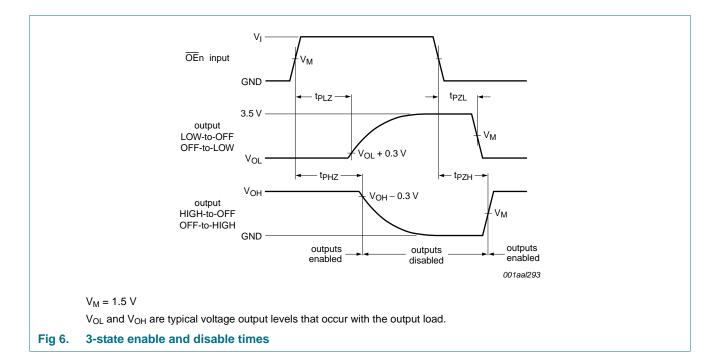


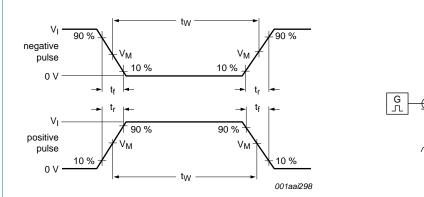
V_M = 1.5 V

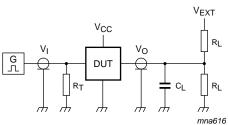
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 5. Propagation delay input (An) to output (Yn)

10-bit buffer/line driver; non-inverting; 3-state







a. Input pulse definition

b. Test circuit

Test data and V_{EXT} levels are given in <u>Table 8</u>.

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_{T} = Termination resistance should be equal to output impedance Z_{o} of the pulse generator.

 V_{EXT} = Test voltage for switching times.

Fig 7. Test circuit for measuring switching times

Table 8. Test data

Input				Load		V _{EXT}		
V_{l}	f _l	t _W	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
3.0 V	1 MHz	500 ns	\leq 2.5 ns	50 pF	500Ω	open	open	7.0 V

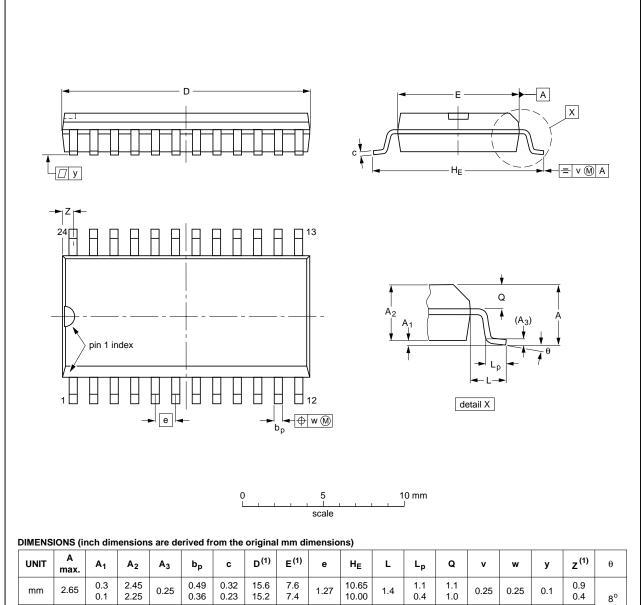
74ABT827 NXP Semiconductors

10-bit buffer/line driver; non-inverting; 3-state

12. Package outline

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	ø	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	15.6 15.2	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.61 0.60	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	JEITA		ISSUE DATE
SOT137-1	075E05	MS-013				-99-12-27 03-02-19

Fig 8. Package outline SOT137-1 (SO24)

74ABT827

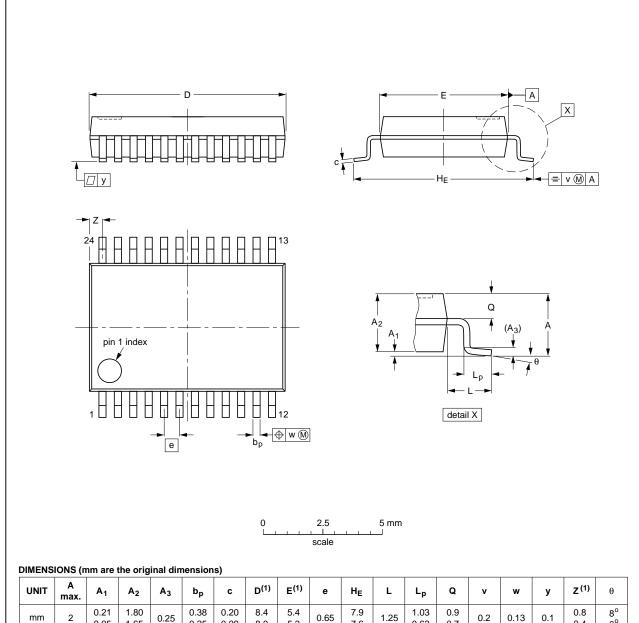
All information provided in this document is subject to legal disclaimers.

74ABT827 **NXP Semiconductors**

10-bit buffer/line driver; non-inverting; 3-state

SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	C	D ⁽¹⁾	E ⁽¹⁾	Ф	HE	L	Lp	ø	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	8.4 8.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.8 0.4	8° 0°

Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT340-1		MO-150			99-12-27 03-02-19

Fig 9. Package outline SOT340-1 (SSOP24)

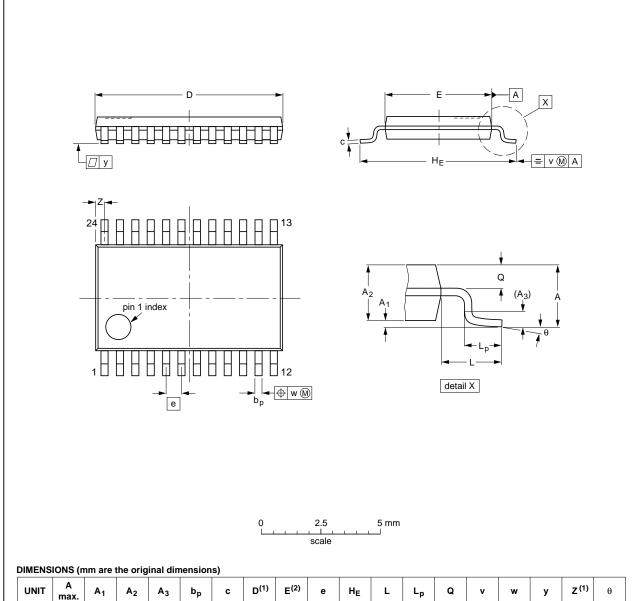
74ABT827

All information provided in this document is subject to legal disclaimers.

10-bit buffer/line driver; non-inverting; 3-state

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1



						٠,												
UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

VERSION IEC JEDEC JEITA PROJECTION SOT355-1 MO-153	OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE		
SO(355-1) $MO-153$ $MO-153$ $MO-153$	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
03-02-19	SOT355-1		MO-153				99-12-27 03-02-19	

Fig 10. Package outline SOT355-1 (TSSOP24)

74ABT82

All information provided in this document is subject to legal disclaimers.

10-bit buffer/line driver; non-inverting; 3-state

13. Abbreviations

Table 9. Abbreviations

Acronym	Description
BiCMOS	Bipolar Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 10. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74ABT827 v.5	20111107	Product data sheet	-	74ABT827 v.4
Modifications:	 Legal pages 	s updated.		
74ABT827 v.4	20100401	Product data sheet	-	74ABT827 v.3
74ABT827 v.3	20100224	Product data sheet	-	74ABT827 v.2
74ABT827 v.2	19980116	Product specification	-	74ABT827 v.1
74ABT827 v.1	19950906	Product specification	-	-

10-bit buffer/line driver; non-inverting; 3-state

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

15.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or

malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

74ABT827

All information provided in this document is subject to legal disclaimers.

10-bit buffer/line driver; non-inverting; 3-state

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

16. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

74ABT827 **NXP Semiconductors**

10-bit buffer/line driver; non-inverting; 3-state

17. Contents

1	General description 1
2	Features and benefits
3	Ordering information 1
4	Functional diagram 2
5	Pinning information 3
5.1	Pinning
5.2	Pin description
6	Functional description 3
6.1	Function table
7	Limiting values 4
8	Recommended operating conditions 4
9	Static characteristics 5
10	Dynamic characteristics 6
11	Waveforms 6
12	Package outline 8
13	Abbreviations
14	Revision history 11
15	Legal information
15.1	Data sheet status
15.2	Definitions 12
15.3	Disclaimers
15.4	Trademarks13
16	Contact information
17	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Buffers & Line Drivers category:

Click to view products by NXP manufacturer:

Other Similar products are found below:

5962-9217601MSA 634810D 875140G HEF4022BP HEF4043BP NL17SG125DFT2G NL17SZ126P5T5G NLU1GT126CMUTCG
NLU3G16AMX1TCG NLV27WZ125USG MC74HCT365ADTR2G BCM6306KMLG 54FCT240CTDB Le87401NQC Le87402MQC
028192B 042140C 051117G 070519XB 065312DB 091056E 098456D NL17SG07DFT2G NL17SG17DFT2G NL17SG34DFT2G
NL17SZ07P5T5G NL17SZ125P5T5G NLU1GT126AMUTCG NLV27WZ16DFT2G 5962-8982101PA 5962-9052201PA 74LVC07ADR2G
MC74VHC1G125DFT1G NL17SH17P5T5G NL17SZ125CMUTCG NLV17SZ07DFT2G NLV37WZ17USG NLVHCT244ADTR2G
NC7WZ17FHX 74HCT126T14-13 NL17SH125P5T5G NLV14049UBDTR2G NLV37WZ07USG 74VHC541FT(BE) RHFAC244K1
74LVC1G17FW4-7 74LVC1G126FZ4-7 BCM6302KMLG 74LVC1G07FZ4-7 74LVC1G125FW4-7